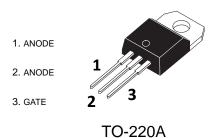


Description

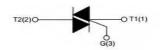
The BTA16 Triac series are suitable for general purpose mains power AC switching. They can be used as ON/OFF function in applications such as static relays, heating regulation or induction motor starting circuit. They are also recommended for phase control operations in light dimmers and appliance motors speed controllers.



Main Fetures

Symbol	value	unit
I _{T(RMS)}	16	Α
V_{DRM}/V_{RRM}	600	V
I _{TSM}	160	Α

10-2207



Absolute maximum ratings

Symbol	Param	Value	Unit		
I _{T(RMS)}	RMS on-state current (full sine wave)			16	А
l-o	Non repetitive surge peak on-state current	F = 50 Hz	t _p = 20 ms	160	A
I _{TSM}	(full cycle,Tj initial = 25 °C)	F = 60 Hz	t _p = 16.7 ms	168] ^
l ² t	I ² t value for fusing	t _p = 10 ms	144	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$	F = 120 Hz	50	A/µs	
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage	t _p = 10 ms	T _j = 25 °C	V _{DRM} /V _{RRM} + 100	V
I _{GM}	Peak gate current	4	Α		
P _{G(AV)}	Average gate power dissipation	1	W		
T _{stg}	Storage junction temperature range	-40 to +150	°C		
Tj	Operating junction temperature range	-40 to +125	°C		



Static Electrical Characteristics

Symbol	Test conditions	Tj		Value	Unit
V _T ⁽¹⁾	I_{TM} = 22.5 A, t_p = 380 μ s	25 °C	Max.	1.55	V
V _{TO} ⁽¹⁾	threshold on-state voltage	125 °C	Max.	0.85	V
R _D ⁽¹⁾	Dynamic resistance	125 °C	Max.	25	mΩ
I _{DRM} /I _{RRM}	V _{DRM} = V _{RRM}	25 °C	Max.	5	μΑ
I I I I I I I I I I I I I I I I I I I	V DKM - V KKM	125 °C	iviax.	2	mA

^{1.} For both polarities of A2 referenced to A1

Electrical Characteristics

 $(T_j = 25 \text{ °C}, \text{ unless otherwise specified}) - \text{standard (4 quadrants)}$

Symbol	Parameters	Quadrant		BTA16	Unit
I _{GT} ⁽¹⁾		1 - 11 - 111	N.4	25	mA
'GT\''	$V_D = 12 \text{ V}, R_L = 33 \Omega$	IV	Max.	50	IIIA
V _{GT}		All	Max.	1.3	V
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 125 \text{ °C}$	All	Min.	0.2	V
I _H ⁽²⁾	I _T = 500 mA		Max.	25	mA
ΙL	I _G = 1.2 I _{GT}	I - III - IV	Max.	40	mA
	16 - 1.2 161	II	Max.	80	111/4

Symbol	Parameters	Quadrant		BTA16	Unit
dV/dt ⁽²⁾	$V_D = 67 \% V_{DRM}$ gate open, $T_j = 125 °C$		Min.	200	V/µs
(dV/dt)c ⁽²⁾	(dl/dt)c = 7 A/ms, T _j = 125 °C		Min.	5	V/µs

^{1.} Minimum I_{GT} is guaranteed at 5 % of I_{GT} max.

^{2.} For both polarities of A2 referenced to A1

Electrical Characteristics

$(T_j = 25 \text{ °C}, \text{ unless otherwise specified})$ - Snubberless and logic level (3quadrants)

Symbol	Parameters	Quadrant		BTA16	Unit
I _{GT} ⁽¹⁾	V _D = 12 V, R _I = 30 Ω		Max.	35	mA
V _{GT}	VD = 12 V, INL = 30 12	1 - 11 - 111	Max.	1.3	٧
V _{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 125 \text{ °C}$		Min.	0.2	٧
I _H ⁽²⁾	I _T = 500 mA			35	mA
l _l	I _G = 1.2 I _{GT}	I - III	Max.	50	
'L		Max.	60	mA	
(dV/dt) ⁽²⁾	VD = 67 % V _{DRM} gate open, T _j = 125 °C		Min.	500	V/µs
	$(dV/dt)c = 0.1 V/\mu s$, $T_j = 125 °C$			8.5	
(dl/dt)c ⁽²⁾	$(dI/dt)c^{(2)}$ $(dV/dt)c = 10 V/\mu s$, $T_j = 125 °C$ Without snubber, $T_j = 125 °C$		Min.	3.0	A/ms
				8.5	

^{1.} Minimum I_{GT} is guaranteed at 5 % of I_{GT} max.

Thermal resistance

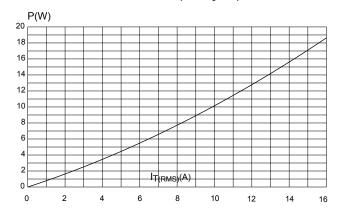
Symbol	Parameters	Value	Unit
R _{th(j-c)}	Max. junction to case (AC)	2.1	°C/W
R _{th(j-a)}	Junction to ambient	60	C/VV

^{2.} For both polarities of A2 referenced to A1

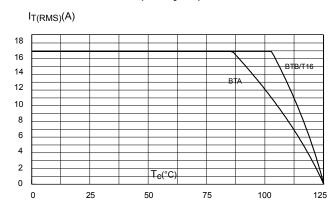


Characteristics (curves)

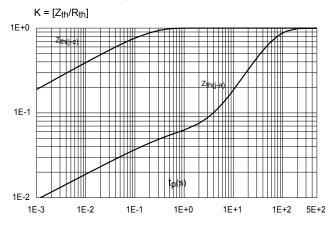
Maximum power dissipation versus on-state RMS current (full cycle)



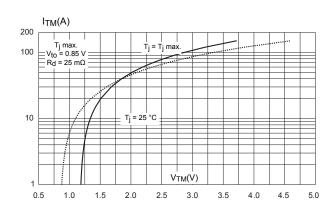
RMS on-state current versus case temperature (full cycle)



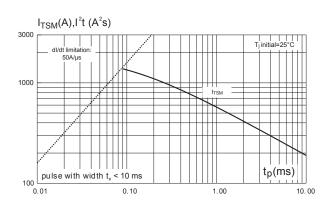
Relative variation of thermal impedance versus pulse duration



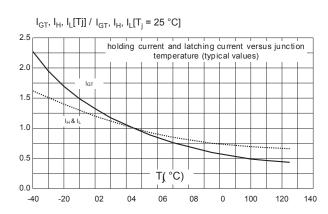
On-state characteristics (maximum values)



Non-repetitive surge peak on-state current for a sinusoidal

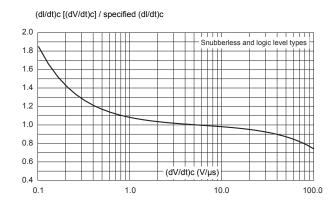


Relative variation of gate trigger current

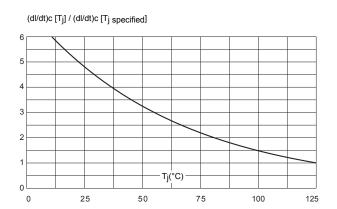




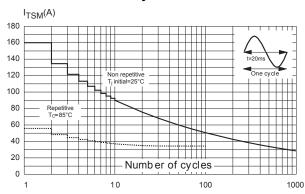
Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)



Relative variation of critical rate of decrease of main current versus (junction temperature (typical values)

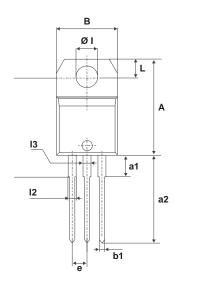


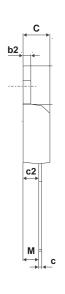
Surge peak on-state current versus number of cycles





Package Information TO-220A





	Dimensions					
Ref.	Mi	Illimete	rs	s Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
В	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
С	4.40		4.60	0.173		0.181
с1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
е	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
14	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
12	1.14		1.70	0.044		0.066
13	1.14		1.70	0.044		0.066
М	·	2.60			0.102	



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